

HEAST - [10555651.wsp:1]

FileViewEditToolsWindowHelp

Drafts

Pending

Active

L1: (1076) semiconductor same (package or device or assembly) same multilayer same dielectric sam...

L2: (202795) bias same control

L3: (118146) ground same conductor

L4: (154904) ground same via

L5: (144755) resistance same film same surface

L6: (56505) electromagnetic same (shield or shielded or shielding)

L8: (4) 3 and 7

L7: (38) 1 and 2

L9: (23) Combined citation search 1

L10: (50) (US-4403208-\$ or US-4947171-\$ or US-5877802-\$ or US-5942957-\$ or US-6160773-\$ or US-554...

L11: (3) MATSUO-KOICHI-\$ in.

L12: (0) TAMAKI-TSUTOMU-\$ in.

L13: (1) SUZUKI-TAKUYA-\$ in.

L14: (1) (semiconductor and (package or device or assembly) and multilayer and dielectric and sub...

L15: (7241) ((342/175) or (342/70) or (342/109) or (343/700MS)).CCLS.

L17: (4) 1 and 16

L16: (6004) 15 and @ad<="20050324"

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10555651_results

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OACS UDC (1)

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US-PGPUS:USPAT:USDCR:EPUS:EPO:JPO:DERWENT:ISM_T08

Default operator: |OR

Highlight all hit terms initially

342/175

342/70

342/109

343/700MS

Document 1

Search-By Pages

Title

Inventor

Current OC

	Search Terms	Total	USPAT	US-PGP	EPO	JPO	Derwent
1	342/109	611					
2	342/175	1184					
3	342/70	1184					
4	343/700MS	4653					
5	(342/109 OR 342/175 OR 342/70 OR 343/700MS)	7241					

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